Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.34$ V at $I_F = 2.5$ A



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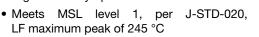
DESIGN SUPPORT TOOLS



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 5.0 A				
V _{RRM}	45 V				
I _{FSM}	100 A				
V _F at I _F = 5.0 A	0.41 V				
T _{OP} max. (AC mode)	150 °C				
T _J max. (DC forward current)	200 °C				
Package	D ² PAK (TO-263AB)				
Circuit configurations	Common cathode				

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation



- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER			VBT1045CBP	UNIT		
Maximum repetitive peak reverse voltage			45	V		
Maximum average forward rectified current (fig. 1)	per device	I (1)	10	А		
Maximum average for ward rectilied current (ng. 1)	per diode	I _{F(AV)} ⁽¹⁾	5			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			100	А		
Operating junction and storage temperature range (AC mode)			-40 to +150	°C		
Junction temperature in DC forward current without reverse bias, $t \leq 1\ h$			≤ 200	°C		

Notes

(1) With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

ELECTRICAL CHARACTERISTICS ($T_A = 25 \degree C$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 2.5 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V	
	I _F = 5.0 A			0.49	0.58		
	I _F = 2.5 A	T _A = 125 °C		0.34	-		
	I _F = 5.0 A			0.41	0.50		
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	500	μA	
		T _A = 125 °C		5	15	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

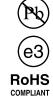
⁽²⁾ Pulse test: Pulse width \leq 40 ms

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	VBT1045CBP	UNIT		
Typical thermal resistance	per diode	P	3.5	°C/W		
	per device	$R_{ extsf{ heta}JC}$	2.5	0/11		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-263AB	VBT1045CBP-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	VBT1045CBP-E3/8W	1.38	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

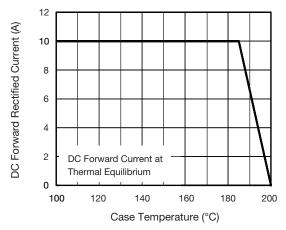


Fig. 1 - Maximum Forward Current Derating Curve

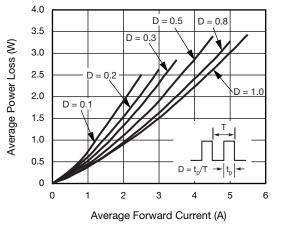


Fig. 2 - Forward Power Loss Characteristics Per Diode

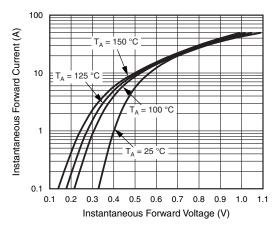


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

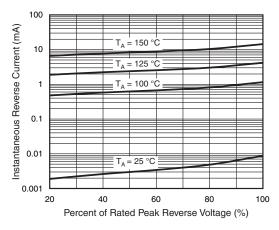
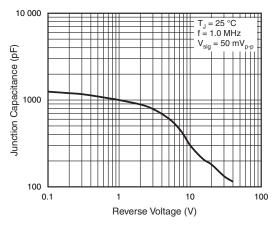


Fig. 4 - Typical Reverse Characteristics Per Diode



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Fig. 5 - Typical Junction Capacitance Per Diode

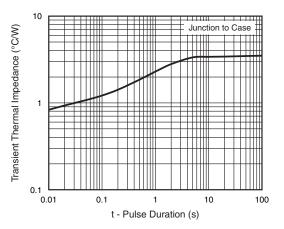
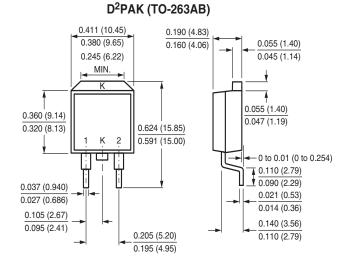
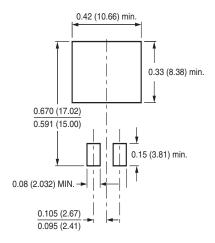


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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